

Optimization study of a crystal-based positron source for FCC-ee

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Outlook

- Brief review of crystal-based positron sources schemes
- Novel optimization approach of a crystal-based positron source through an experimentally validated simulation framework
- Optimized solution for FCC-ee positron source



FCC / FCC-ee and Positron Sources

- Future CERN collider post LHC ~ 91 Km of circumference
- Stages: FCC-ee, Fcc-eh, FCC-hh
- High luminosity: • up to $230 \times 10^{34} cm^{-2} s^{-1}$

| FCC-ee Operation Mode | Final Energy [GeV] | Beam Current [mA] | | | | | | | |
|---|-----------------------|----------------------|--|--|--|--|--|--|--|
| Z | 45 | 1270 | | | | | | | |
| W | 80 | 137 | | | | | | | |
| Н | 120 | 26.7 | | | | | | | |
| ttbar | 182.5 | 4.9 | | | | | | | |
| It is the most demaning for the positron source | | | | | | | | | |



Conventional scheme of a positron source



Positron source set a critical constraint for the peak and average current -> Luminosity Constraint! Expecially for future Linacs -> crystal-based positrons sources

FE activity in crystal-based positron sources born in past INFN projects STORM (2021-22) and RD-MUCOL (for LEMMA). Currently, we are in RD-FCC, e+BOOST (bando PRIN2022), CHART PI

Crystal-based positron source

Originally proposed by R. Chehab, A. Variola, V. Strakhovenko and X. Artru

R. Chehab et al., in Proc. of the 1989 IEEE Particle Accelerator Conf., 1989, pp. 283–285



Use of coherent effects in oriented crystals: channeling and over barrier motion (and photon generation) → typical angular range of few mrad at few GeV for <111> axis in W (axial potential is stronger and limits electron dechanneling, contrary to planar alignment)

Novel production scheme for positron sources:

- Enhancement of (soft) photon generation in (high Z) oriented crystals → enhancement of pair production / positron charge
- Lower energy deposit and PEDD (with hybrid scheme) in target →
 lower heating and thermo-mechanical stress (target reliability)

Hybrid scheme

Idea of X. Artru et al., NIM B 266 (2008) 3868 Test at KEK with a W crystal, NIM B 402 (2017) 58



Planar vs Axial Channeling

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Ó

x (Å)

2



Trajectory of one 530 MeV/c positron interacting with a 0.03 mm bent (97 μ rad) Si crystal oriented along (111) planes

Electrons impinging at a small-angle w.r.t. **an axis of a high-Z crystal** (**higher U**₀ (~ 1 keV) -> stronger lattice effects and θ_L (~ 1 mrad @ 1 GeV) -> higher acceptance w.r.t. planes), are **mostly over-barrier** -> the motion is not periodic, but there are high field gradients -> high local deflection -> **sinchrotronlike radiation**, with enanchement of **soft photons emission**.



Trajectory of one **2.86 GeV/c electron** interacting with a **0.3 mm W** crystal oriented along **<111> axis**

It is important to have a reliable simulation tool of particle interactions in oriented crystals.

Channeling simulation in Geant4: novel *G4ChannelingFastSimModel* and *G4BaierKatkov* classes were developed and embedded in Geant4 (since 11.2.0 version). These models are based on CRYSTALRAD (by A Sytov)

Main conception: simulation of classical trajectories of charged particles in a crystal in averaged atomic potential of planes or axes [1]. Multiple and single scattering, as well as ionization, simulation at every step. Photon emission simulated through MC integration of Baier-Katkov formula [2-5].



Validation of Geant4 channeling model against experimental data



EIC-PATHFINDER-OPEN TECHNO-CLS (GA 101046458)



Set-up similar to the one desribed in: L. Bandiera et al., Eur. Phys. J. C 82, 699 (2022), where there is a also compoarison with simulations in which coherent interactions of e- in the W crystal were **simulated with CRYSTAL code** (by V. Tikhomirov).

Radiative energy loss measured by the Ecal



Simulation performed with Geant4 taking advantage of the novel *G4BaierKatkov* and *G4ChannelingFastSimModel*.

Validation of our Geant4 models at an energy significant for FCC-ee positron source.

Simulation of the e+ production stage: **PositronSource** application (now it is on GitHub and will be an extended example of Geant4)



- It allow us to simulate both a conventional and a crystal-based positron source.
- The code relies on *G4ChannelingFastSimModel*. Alternatively, a phase-space (e.g. from CRYSTAL code) can be imported.
- A collimator or a magnetic field can be included in the simulation (improved hybrid scheme).
- Scoring of particle phase space at exit of crystals and of energy distribution inside them (BoxMesh or custom VoxelScorer).
- The application is fully compatible with **multi-threading** and everything can be controlled via **macro commands**.
- A set of python scripts are available for output analysis and positron phase-space export for tracking in the pre-injector.

FCC-ee positron source requirement and injector layout (current baseline)



1 mm

 $\gtrsim 0.5 \text{ mm}$

To fulfil the requirements for the Z mode \rightarrow 5.4 nC e+/bunch at the DR* \rightarrow 13.5 nC e+/bunch at the exit of the Positron Linac, considering 60% of losses due to transport, collimation and injection in the DR (safety margin of 2.5). This e+ charge has to be obtained from the following e- drive beam

Repetition rate

Beam power

ש'

Bunch length

Bunch transverse size

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100 Hz

 \sim 6.4 kW (max)

Simulation of the capture / pre-acceleration stages

- After the production, the pair is captured in the pre-injector system.
- The main stages of the pre-injector are simulated through a set of dedicated *RF-Track** scripts.

*https://doi.org/10.5281/zenodo.4580369

Collaboration with FCC-ee Injection Group - positron source task (leader I. Chaikovska (IJCLab)). MoU signed between in INFN Ferrara and IJCLab in Sept. 2022





We measure the performances of e⁺ sources **before the damping ring** where cooling occurs (2.5 safety factor)

Simulation of the capture / pre-acceleration stages



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Simulation of the capture / pre-acceleration stages



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Simulation (Geant4 + RF-Track) results for 2.86 GeV FCC-ee positron source (aftet the positron linac)





Simulation studies converge to a **total W thickness of about 12 mm** (~3.4 X₀) \rightarrow need **D~0** (2 targets) or **a one thick singlecrystal**.

The Single Crystal **PEDD** is **acceptable** considering FCC-ee parameters [max 10.5 J/g/pulse].

We can use **just one device** to obtain +8% e+ yield and -15% power at «**zero cost**».

Integration and operation of the crystal target: effect of misalignments and high temperature

1.10

1.05

1.00

Single-Tungsten-Crystal Source, e- beam at 2.86 GeV (r.m.s. size 1.0 mm). 12 mm.

high temperature (~ 600 K) - Tolerance to misalignments

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- **Crystal heating:** The photon yield drops ٠ insignificantly for temperatures ~ 600 K
- **Crystal alignment:** No goniometer inside the AMD-HTS. The typical precision of the pre-alignment **procedure** $\sim 1 \text{ mrad}$ (margins of improvement).
- **Crystal guality:** The crystalline guality of ~ 10 mm ٠ thick W sample is lower than for a thin sample \rightarrow lower yield, but larger acceptance angles.



And what about the other lepton colliders?

| Project | CLIC | ILC | LHeC (pulsed) | LEMMA | CEPC | FCC-ee |
|---|-----------|------------|-----------------|--------|-------|--------|
| Final e ⁺ energy [GeV] | 190 | 125 | 140 | 45 | 45 | 45.6 |
| Primary e ⁻ energy [GeV] | 5 | 128** (3*) | 10 | - | 4 | 6 |
| Number of bunches per pulse | 352 | 1312 (66*) | 10 ⁵ | 1000 | 1 | 2 |
| Required charge [10 ¹⁰ e ⁺ /bunch] | 0.4 | 3 | 0.18 | 50 | 0.6 | 2.1 |
| Horizontal emittance $\gamma \epsilon_x$ [µm] | 0.9 | 5 | 100 | — | 16 | 24 |
| Vertical emittance $\gamma \epsilon_y$ [µm] | 0.03 | 0.035 | 100 | _ | 0.14 | 0.09 |
| Repetition rate [Hz] | 50 | 5 (300*) | 10 | 20 | 50 | 200 |
| e ⁺ flux [10 ¹⁴ e ⁺ /second] | 1 | 2 | 18 | 10-100 | 0.003 | 0.06 |
| Polarization | No/Yes*** | Yes/(No*) | Yes | No | No | No |

I. Chaikovska et al., Positron sources: from conventional to advanced accelerator concepts-based colliders 2022 JINST 17 P05015

* The parameters are given for the electron-driven positron source being under consideration.

** Electron beam energy at the end of the main electron linac taking into account the looses in the undulator.

*** Polarization is considered as an upgrade option.

<u>Linear Collider projects</u>: high request for polarization, requested intensity should be produced in "one shot". <u>Circular Collider projects</u>: polarization is under discussion; requirements are relaxed due to stacking and top-up injection

- The future Linear Colliders CLIC and ILC designs foresee a positron rate higher than FCC-ee by a factor 20 ÷ 30;
- The LHeC and LEMMA proposals aim at extremely high rates, about two order of magnitude higher than CLIC and ILC.

Improved hybrid source...



PEDD decreased in case of hybrid, while yield was equal or higher w.r.t. conventional (even if more loss within CS). The scheme with magnet is the baseline for CLIC and was proposed for LHeC/LEMMA (several hybrid targets in parallel with cooled, rotating/granular converter)

Conclusions

- A **reliable simulation framework** from the target to the positron linac **is available**.
- The design of a crystal-based positron source for the FCC-ee @ 2.86 GeV is well advanced (otpimization of the capture section of pre-injector still ongoing). The goal is to include the design in the next FCC CDR.
- Next steps: integration studies with potential proof-ofprinciple at P³ experiment @ PSI (and future CHART projects).
- **Missing**: test of positron production with single crystal without goniometer and of radiation resistance.
- The **PositornSource application** allow us to investigate also the improved hybrid scheme useful for very intense positron sources.



Thank you



My email address: paterno@fe.infn.it

Back-up slides

Conventional, room temperature

W, e- beam at 2.86 GeV (r.m.s. size 1.0 mm), room temperature

| Case | photon Yield | neutron Yield | Target Yield | e+ beam mean size [mm] | Edep [GeV/e-] | PEDD [MeV / (mm^3 e-)] | AMD Yield (R=30 cm) | Collection Efficiency [%] | Yield RF | Emean RF [MeV] | Espread RF [%] | Bunch Length [mm] | Accepted Yield | Bunch Charge [nC] | PEDD [J/g/pulse] | Power Deposited [kW] |
|--------------|-----------------|------------------|-----------------|------------------------------|------------------|------------------------------|------------------------|---------------------------------|----------|-------------------|-------------------|-------------------------|-------------------|-------------------------|---------------------|----------------------------|
| conventional | 150.04 | 0.34 | 7.09 | 1.16 | 0.65 | 7.42 | 6.42 | 90.61 | 4 | 214.52 | 16.54 | 2.73 | 3.04 | 4.45 | 6.84 | 1.15 |
| W5.0mm | 26.33 | 0.03 | 2.33 | 1.03 | 0.05 | 2.51 | 2.21 | 94.82 | 1.09 | 212.74 | 34.67 | 2.61 | 0.85 | 15.92 | 8.3 | 0.31 |
| W6.0mm | 35.8 | 0.04 | 3.04 | 1.03 | 0.07 | 3.44 | 2.86 | 94.05 | 1.45 | 212.7 | 30.33 | 2.62 | 1.12 | 12.11 | 8.65 | 0.36 |
| W7.0mm | 47.15 | 0.07 | 3.79 | 1.06 | 0.11 | 3.77 | 3.54 | 93.46 | 1.85 | 212.29 | 25.27 | 2.65 | 1.44 | 9.36 | 7.33 | 0.41 |
| W8.0mm | 59.92 | 0.09 | 4.53 | 1.07 | 0.15 | 4.58 | 4.2 | 92.76 | 2.27 | 212.32 | 22.64 | 2.68 | 1.76 | 7.66 | 7.29 | 0.47 |
| W9.0mm | 72.68 | 0.13 | 5.15 | 1.09 | 0.2 | 5.34 | 4.75 | 92.25 | 2.64 | 212.6 | 20.6 | 2.67 | 2.04 | 6.62 | 7.35 | 0.53 |
| W10.0mm | 86.14 | 0.14 | 5.73 | 1.08 | 0.26 | 6.22 | 5.27 | 91.87 | 3 | 212.3 | 19.19 | 2.69 | 2.31 | 5.85 | 7.57 | 0.6 |
| W11.0mm | 100.62 | 0.18 | 6.25 | 1.11 | 0.33 | 6.58 | 5.7 | 91.3 | 3.32 | 213.33 | 17.64 | 2.71 | 2.56 | 5.27 | 7.21 | 0.69 |
| W12.0mm | 113.86 | 0.21 | 6.62 | 1.1 | 0.4 | 6.9 | 6.03 | 91.15 | 3.58 | 213.63 | 18.16 | 2.71 | 2.76 | 4.89 | 7.01 | 0.78 |
| W13.0mm | 127.03 | 0.25 | 6.89 | 1.13 | 0.48 | 7.32 | 6.27 | 90.88 | 3.83 | 213.67 | 15.72 | 2.7 | 2.92 | 4.63 | 7.04 | 0.88 |
| W14.0mm | 139.18 | 0.28 | 7.05 | 1.14 | 0.56 | 7.65 | 6.4 | 90.7 | 3.96 | 214.15 | 15.89 | 2.73 | 3.01 | 4.49 | 7.14 | 1.01 |
| W15.0mm | 150.04 | 0.34 | 7.09 | 1.16 | 0.65 | 7.42 | 6.42 | 90.61 | 4 | 214.47 | 16.55 | 2.72 | 3.02 | 4.47 | 6.89 | 1.16 |
| W16.0mm | 160.18 | 0.39 | 7.1 | 1.19 | 0.74 | 7.53 | 6.41 | 90.36 | 4.07 | 214.92 | 15.58 | 2.73 | 3.07 | 4.4 | 6.88 | 1.29 |
| W17.0mm | 169.33 | 0.45 | 7.05 | 1.19 | 0.83 | 7.67 | 6.35 | 90.08 | 4.07 | 215.15 | 15.43 | 2.72 | 3.04 | 4.44 | 7.08 | 1.47 |
| W18.0mm | 177.16 | 0.45 | 6.85 | 1.21 | 0.92 | 7.89 | 6.16 | 89.9 | 3.97 | 215.45 | 15.49 | 2.76 | 2.96 | 4.56 | 7.48 | 1.68 |
| W19.0mm | 183.81 | 0.51 | 6.69 | 1.24 | 1.01 | 7.43 | 6.01 | 89.72 | 3.91 | 215.98 | 15.73 | 2.75 | 2.89 | 4.67 | 7.21 | 1.89 |
| W20.0mm | 188.43 | 0.57 | 6.4 | 1.23 | 1.1 | 7.69 | 5.73 | 89.41 | 3.76 | 215.83 | 15.44 | 2.77 | 2.79 | 4.84 | 7.73 | 2.13 |

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Single Crystal, room temperature

Single-Tungsten-Crystal Source, e- beam at 2.86 GeV (r.m.s. size 1.0 mm), room temperature

| Case | photon Yield | neutron Yield | Target Yield | e+ beam mean size [mm] | Edep [GeV/e-] | PEDD [MeV / (mm^3 e-)] | AMD Yield (R=30 cm) | Collection Efficiency [%] | Yield RF | Emean RF [MeV] | Espread RF [%] | Bunch Length [mm] | Accepted Yield | Bunch Charge [nC] | PEDD [J/g/pulse] | Power Deposited [kW] |
|--------------|-----------------|------------------|-----------------|------------------------------|------------------|------------------------------|------------------------|---------------------------------|----------|-------------------|-------------------|-------------------------|-------------------|-------------------------|---------------------|----------------------------|
| conventional | 150.04 | 0.34 | 7.09 | 1.16 | 0.65 | 7.42 | 6.42 | 90.61 | 4 | 214.52 | 16.54 | 2.73 | 3.04 | 4.45 | 6.84 | 1.15 |
| W8.0mm | 97.31 | 0.15 | 6.53 | 1.09 | 0.28 | 6.94 | 5.99 | 91.79 | 3.5 | 213.03 | 20.85 | 2.69 | 2.71 | 4.98 | 7.18 | 0.56 |
| W9.0mm | 112.33 | 0.2 | 7 | 1.1 | 0.35 | 7.54 | 6.41 | 91.53 | 3.85 | 213.45 | 19.41 | 2.69 | 2.95 | 4.58 | 7.17 | 0.65 |
| W10.0mm | 126.51 | 0.23 | 7.31 | 1.1 | 0.43 | 8.04 | 6.66 | 91.03 | 4.08 | 213.94 | 17.8 | 2.71 | 3.11 | 4.34 | 7.25 | 0.75 |
| W11.0mm | 140.35 | 0.27 | 7.52 | 1.13 | 0.52 | 8.15 | 6.84 | 90.93 | 4.26 | 214.09 | 16.71 | 2.71 | 3.24 | 4.17 | 7.06 | 0.87 |
| W12.0mm | 153.52 | 0.31 | 7.58 | 1.17 | 0.61 | 8.11 | 6.87 | 90.71 | 4.33 | 214.61 | 17.54 | 2.73 | 3.27 | 4.13 | 6.96 | 1.01 |
| W13.0mm | 164.75 | 0.37 | 7.5 | 1.16 | 0.71 | 8.32 | 6.79 | 90.52 | 4.35 | 214.61 | 15.69 | 2.73 | 3.28 | 4.12 | 7.12 | 1.17 |
| W14.0mm | 174.22 | 0.41 | 7.42 | 1.19 | 0.81 | 8.24 | 6.7 | 90.25 | 4.32 | 214.87 | 16.02 | 2.76 | 3.25 | 4.16 | 7.12 | 1.34 |
| W15.0mm | 182.76 | 0.47 | 7.27 | 1.2 | 0.9 | 8.28 | 6.55 | 90.04 | 4.29 | 215.5 | 15.3 | 2.78 | 3.2 | 4.21 | 7.25 | 1.52 |
| W16.0mm | 189.18 | 0.51 | 6.98 | 1.23 | 1 | 8.4 | 6.27 | 89.83 | 4.12 | 216.04 | 15.17 | 2.77 | 3.05 | 4.43 | 7.74 | 1.77 |

Single Crystal – HT, misalignment

Single-Tungsten-Crystal Source, e- beam at 2.86 GeV (r.m.s. size 1.0 mm), 12 mm, high temperature (~ 600 K) - Tolerance to misalignments

| Case | photon Yield | neutron Yield | Target Yield | e+ beam mean size [mm] | Edep [GeV/e-] | PEDD [MeV / (mm^3 e-)] | AMD Yield (R=30 cm) | Collection Efficiency [%] | Yield RF | Emean RF [MeV] | Espread RF [%] | Bunch Length [mm] | Accepted Yield | Bunch Charge [nC] | PEDD [J/g/pulse] | Power Deposited [kW] |
|-----------------|-----------------|------------------|-----------------|------------------------------|------------------|------------------------------|------------------------|---------------------------------|----------|-------------------|-------------------|-------------------------|-------------------|-------------------------|---------------------|----------------------------|
| conventional | 150.04 | 0.34 | 7.09 | 1.16 | 0.65 | 7.42 | 6.42 | 90.61 | 4 | 214.52 | 16.54 | 2.73 | 3.04 | 4.45 | 6.84 | 1.15 |
| 0 mrad, 300K | 153.52 | 0.31 | 7.58 | 1.17 | 0.61 | 8.11 | 6.87 | 90.71 | 4.33 | 214.61 | 17.54 | 2.73 | 3.27 | 4.13 | 6.96 | 1.01 |
| 0 mrad | 150.15 | 0.31 | 7.49 | 1.16 | 0.6 | 8.21 | 6.79 | 90.65 | 4.28 | 214.18 | 17.5 | 2.72 | 3.23 | 4.17 | 7.12 | 1 |
| 1 mrad | 148.01 | 0.31 | 7.43 | 1.14 | 0.59 | 8.18 | 6.74 | 90.63 | 4.19 | 214.37 | 15.97 | 2.72 | 3.18 | 4.25 | 7.22 | 0.99 |
| 2 mrad | 146.04 | 0.29 | 7.43 | 1.16 | 0.57 | 7.98 | 6.73 | 90.64 | 4.2 | 214.35 | 16.2 | 2.73 | 3.19 | 4.23 | 7.02 | 0.97 |
| 3 mrad | 143.27 | 0.28 | 7.4 | 1.15 | 0.55 | 7.88 | 6.7 | 90.53 | 4.17 | 214.43 | 16.11 | 2.73 | 3.19 | 4.24 | 6.94 | 0.94 |
| 4 mrad | 140.18 | 0.29 | 7.32 | 1.15 | 0.54 | 7.75 | 6.64 | 90.73 | 4.11 | 214.08 | 15.86 | 2.71 | 3.14 | 4.3 | 6.93 | 0.92 |
| 5 mrad | 137.45 | 0.28 | 7.28 | 1.17 | 0.52 | 7.75 | 6.61 | 90.73 | 4.07 | 214.34 | 16.05 | 2.72 | 3.1 | 4.35 | 7.01 | 0.91 |
| 6 mrad | 133.22 | 0.26 | 7.18 | 1.14 | 0.5 | 8.1 | 6.52 | 90.76 | 3.99 | 214.18 | 16.1 | 2.7 | 3.05 | 4.42 | 7.44 | 0.88 |
| 7 mrad | 127.21 | 0.25 | 7.03 | 1.16 | 0.47 | 7.1 | 6.39 | 90.93 | 3.9 | 213.74 | 16.64 | 2.71 | 2.98 | 4.53 | 6.68 | 0.84 |
| 8 mrad | 122.63 | 0.23 | 6.93 | 1.13 | 0.44 | 7.16 | 6.3 | 90.99 | 3.83 | 214.23 | 17.7 | 2.7 | 2.94 | 4.59 | 6.82 | 0.81 |
| 9 mrad | 120.72 | 0.23 | 6.84 | 1.13 | 0.43 | 7.55 | 6.22 | 91.01 | 3.75 | 213.93 | 15.78 | 2.72 | 2.88 | 4.69 | 7.36 | 0.81 |
| 10 mrad | 118.64 | 0.23 | 6.81 | 1.14 | 0.42 | 7.31 | 6.19 | 90.97 | 3.74 | 213.75 | 17.77 | 2.72 | 2.86 | 4.72 | 7.16 | 0.79 |

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